

	Applicatio	n No.	Applicant(s)	
Notice of Allowability	10/718,459 Examiner	<u> </u>	BUYNOSKI, MATTHEW S.	
	PHUC T. E	ANG	2818	
The MAILING DATE of this communication apperature All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT R of the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAI or other app IGHTS. This	NS) CLOSED in this appropriate communication application is subject to	oplication. If not include n will be mailed in due	ed course. <b>THIS</b>
1. $\boxtimes$ This communication is responsive to <u>November 20, 2003</u> .				
2. The allowed claim(s) is/are 1-23.				
3. $\boxtimes$ The drawings filed on <u>20 November 2003</u> are accepted by	the Examine	er.		
4. ☐ Acknowledgment is made of a claim for foreign priority unall All b) ☐ Some* c) ☐ None of the:  1. ☐ Certified copies of the priority documents have 2. ☐ Certified copies of the priority documents have 3. ☐ Copies of the certified copies of the priority do International Bureau (PCT Rule 17.2(a)).  * Certified copies not received:  Applicant has THREE MONTHS FROM THE "MAILING DATE" noted below. Failure to timely comply will result in ABANDONN THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.  5. ☐ A SUBSTITUTE OATH OR DECLARATION must be submin INFORMAL PATENT APPLICATION (PTO-152) which give 6. ☐ CORRECTED DRAWINGS (as "replacement sheets") must be comply including changes required by the Notice of Draftspers 1) ☐ hereto or 2) ☐ to Paper No./Mail Date  (b) ☐ including changes required by the attached Examiner' Paper No./Mail Date	e been receive been receive cuments have of this comment of this comment. Note the reason(s) at be submitted.	red. red in Application No re been received in this nunication to file a reply application. ne attached EXAMINER why the oath or declar ed. Drawing Review ( PTC	national stage applicated complying with the reconstruction of Nation is deficient.	quirements
Identifying indicia such as the application number (see 37 CFR 1	.84(c)) shoul	be written on the draw	ings in the front (not the	e back) of
each sheet. Replacement sheet(s) should be labeled as such in to 7. DEPOSIT OF and/or INFORMATION about the deposit attached Examiner's comment regarding REQUIREMENT	sit of BIOL	OGICAL MATERIAL	must be submitted.	Note the
<ul> <li>Attachment(s)</li> <li>1. ☑ Notice of References Cited (PTO-892)</li> <li>2. ☐ Notice of Draftperson's Patent Drawing Review (PTO-948)</li> <li>3. ☑ Information Disclosure Statements (PTO-1449 or PTO/SB/neaper No./Mail Date 112003</li> <li>4. ☐ Examiner's Comment Regarding Requirement for Deposit of Biological Material</li> </ul>	6 08), 7 8 9	☐ Interview Summar Paper No./Mail Do. ☐ Examiner's Amend ☐ Examiner's Statem ☐ Other	ate	·
PHU	c T.	DANG EXAMINER	Lunggown	
PR'n	MARY E	XAMINER	W	

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## **DETAILED ACTION**

1. Claims 1-23 are allowed.

2. The following is an examiner's statement of reasons for allowance:

With respect to claim 1, the prior art of record, taken alone or in combination, fails to teach or reasonably suggests a method for manufacturing a memory device, comprising a step of disposing a memory element over the first electrode, the memory element comprising a sulfide derived from sulfur dioxide, in combination with the rest of the limitations of claim 1.

With respect to claim 11, the prior art of record, taken alone or in combination, fails to teach or reasonably suggests a method for manufacturing a memory element, comprising a step of decomposing sulfur dioxide in the presence of hydrogen to form a copper sulfide CuxS film on the major surface, where 1 < X < 2, in combination with the rest of the limitations of claim 11.

With respect to claim 14, the prior art of record, taken alone or in combination, fails to teach or reasonably suggests a method for manufacturing a semiconductor component, comprising a step of disposing a memory element over the first electrode, wherein the memory element comprises sulfur derived from sulfur dioxide, in combination with the rest of the limitations of claim 14.

With respect to claim 17, the prior art of record, taken alone or in combination, fails to teach or reasonably suggests a method for forming a memory material, comprising a step of reacting hydrogen sulfide with copper to form a copper sulfide,  $Cu_XS$ , where  $1 \le X \le 2$ , in combination with the rest of the limitations of claim 17.

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Any comments considered necessary by applicant must be submitted no later than the

payment of the issue fee and, to avoid processing delays, should preferably accompany the issue

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fee. Such submission should be clearly labeled "Comments on Statement of Reasons for

Allowance".

Any inquiry concerning this communication or earlier communications from the examiner

should be directed to Phuc T. Dang whose telephone number is (571) 272-1776. The examiner

can normally be reached on 8:00 am-5:00 pm.

5. If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor,

David C. Nelms can be reached on (571) 272-1787. The fax phone numbers for the organization

where this application or proceeding is assigned are 703-872-9306 for regular communications

and After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding

should be directed to the receptionist whose telephone number is 703-308-0956.

Langghur

Phuc T. Dang

Primary Examiner

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